

<p style="text-align: center;">O I P E J C 37</p> <p style="text-align: center;">MAR 14 2005</p> <p style="text-align: center;">INFORMATION DISCLOSURE STATEMENT BY APPLICANT</p> <p style="text-align: center;">(Multiple sheets used when necessary)</p>		Application No.	10/634,212
		Filing Date	August 5, 2003
		First Named Inventor	Karen Signorini
		Art Unit	2813
SHEET 1 OF 3		Examiner	Jennifer M. Dolan
		Attorney Docket No.	MICRON.249C1DV1

U.S. PATENT DOCUMENTS					
Examiner Initials	Cite No.	Document Number Number - Kind Code (if known) Example: 1,234,567 B1	Publication Date MM-DD-YYYY	Name of Patentee or Applicant	Pages, Columns, Lines Where Relevant Passages or Relevant Figures Appear
<i>JMD</i>	1	3,553,660	01/05/1971	Wolf	
<i>JMD</i>	2	3,623,032	11/23/1971	Schapira	
<i>JMD</i>	3	3,623,035	11/23/1971	Kobayashi et al.	
<i>JMD</i>	4	3,816,909	06/18/1974	Maeda et al.	
<i>JMD</i>	5	3,947,831	03/30/1976	Kobayashi et al.	
<i>JMD</i>	6	4,044,330	08/23/1977	Johnson et al.	
<i>JMD</i>	7	4,060,794	11/29/1977	Feldman et al.	
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<i>JMD</i>	11	4,666,554	05/19/1987	De Wilde et al.	
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<i>JMD</i>	29	5,650,958	07/22/1997	Gallagher et al.	

Examiner Signature <i>Jennifer M. Dolan</i>	Date Considered <i>3/20/03</i>
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	30	5,701,222	12/23/1997	Gill et al.	
	31	5,726,498	03/10/1998	Licata et al.	
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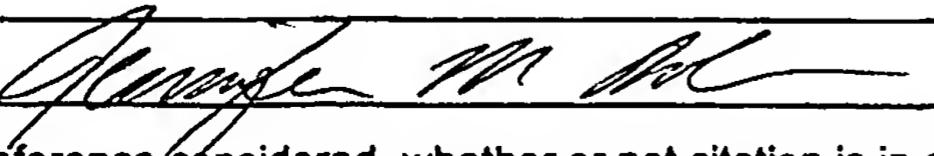
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	55	DE 198 36 567 A1	02/24/2000	Schwarz		
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	57	EP 0 450 911 A2	10/09/1991	Daughton et al.		
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	60	WO 98/20496	05/14/1998	Daughton et al.		
	61	WO 00/19440	04/06/2000	Weber et al.		

NON PATENT LITERATURE DOCUMENTS			
Examiner Initials	Cite No.	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T <sup>1</sup>
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	64	Prinz, Gary, "Magnetoelectronics," <u>Science</u> , Vol. 282, November 27, 1998, pp. 1660-1663.	
	65	Wang, Zhi G. et al., "Feasibility of Ultra-Dense Spin-Tunneling Random Access Memory," <u>IEEE Transactions on Magnetics</u> , Vol. 33, No. 6, November 1997, pp. 4498-4512.	
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